THALES

FEATURES

- 4 to 40 kHz operation
- 170 W at 532 nm
- 220 W at 1064 nm
- Outstanding stabilityM2 between 15 and 40 (on request)
- Compact and ruggedized industrial design
- Options: fiber coupling, integrated attenuator

INDUSTRIAL APPLICATIONS

- Laser OLED Lift-Off
- CFRP Machining
- Silicon Annealing

SCIENTIFIC APPLICATIONS

- Femtosecond amplifier pumping
- Instrumentation
- Scientific pump source for non-linear optics

ETNA HP Diode-Pumped Compact Laser Series





ETNA HP

Diode-pumped compact laser series

Specifications

Wavelength (nm)

Repetition rate (kHz) (1)

Version

The world reference for high average power Nd:YAG laser

Thanks to its unique specifications, outstanding stability, high flexibility and maintenance free operation, the ETNA HP is perfectly suited for industrial environment.

The ETNA HP delivering more than 170W of green power at 10kHz is the best balance choice between high average power, repetition rate and cost requirements.

The ETNA HP is based on Thales latest developments in diode pumping heads renowned for their outstanding power stability. As a unique compromise between energy and repetition rate, the ETNA HP is the best laser solution to mass production requirements for high tech and consumer markets.

Options

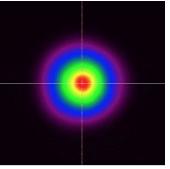
Fibered module for industrial applications including:

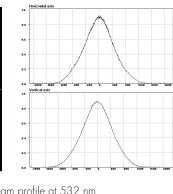
- Calibrated power measurement
- Computer controlled power attenuation (5-99%)
- Fiber optic injection (compatible with industrial fiber optics)
- Security shutter / Water cooled beam dump

Physical characteristics (Size: $H \times W \times L$)

Power supply	80 (31,5) × 60 (23,6) × 83 (32,7)
Cooling unit	60 (23,6) x 44 (17,4) x 83 (32,6)
Laser head	21,3 (8) × 28,5 (11) × 108 (42,5)

* Dimension are given in cm (in)





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Typical Etna HP beam profile at 532 nm

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average Aver

Energy per pulse	> 22	> 15	> 17
Average power (VV) $^{(2)}$	> 220	> 150	> 170
Typical pulse width (ns)	85	50	60
Pulse to pulse energy stability (% rms)	< 1.0	< 1.0	< 1.0
Typical M ²	20 +/- 2.5	15 +/- 2.5	25 +/- 2.5
Beam pointing stability (µrad)	+/- 30	+/- 30	+/- 30
Typical Beam size (mm) at waist position	~ 3.2	~ 2.1	~ 2.7
Beam profile	Multi-mode Gaussian	Multi-mode Gaussian	Multi-mode Gaussian
Polarization	Unpolarized	Vertical	Vertical

IR

1064

4-40

LM

532

8-40

HM

532

4-20

⁽¹⁾ Factory preset at one repetition rate ⁽²⁾ Other average power available on request

Utilities and environment requirements

Voltage		208 – 230 VAC +/-5% single φ		
Frequency	/	50 – 60 Hz		
Water	Flow	> 15 L/min	> 4 gal /min	
	Static pressure	3-5 bars	43.5-72 psi	
	Temperature	15-17°C		
Operating systems		Windows 98, 2000, NT, XP		

Pressit Pressit 196 W at 532 nm MW 0.2% rms over 24 hours 0.2% rms over 24 hours

Long term stability over 30 hours (High M² version)



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